



High Quality Audio , J-FET Input, Dual Operational Amplifier

The MUSES01 is a dual J-FET input high quality audio operational amplifier, which is optimized for high-end audio and professional audio applications with advanced circuitry and layout, unique material and assembled technology by skilled-craftwork.

It is the best for audio preamplifiers, active filters, and line amplifiers with excellent sound.

■ FEATURES

- Operating Voltage
- Output noise
- Input Offset Voltage
- Input Bias Current
- Voltage Gain
- Slew Rate
- Bipolar Technology
- Package Outline

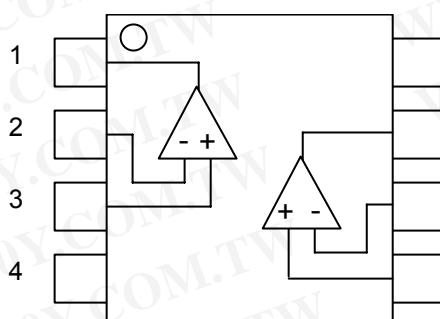
$V_{opr} = \pm 9V$ to $\pm 16V$
 $9.5nV/\sqrt{Hz}$ at $f=1kHz$
0.8mV typ. 5mV max.
200pA typ. 800pA max. at $T_a=25^\circ C$
105dB typ.
12V/ μs typ.

DIP8

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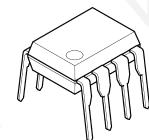
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■ PIN CONFIGURATION



PIN FUNCTION

- | | |
|---|-------------|
| 1 | 1. A OUTPUT |
| 2 | 2. A-INPUT |
| 3 | 3. A +INPUT |
| 4 | 4. V- |
| 5 | 5. B +INPUT |
| 6 | 6. B -INPUT |
| 7 | 7. B OUTPUT |
| 8 | 8.V+ |



MUSES01D

■ PACKAGE OUTLINE



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■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

| PARAMETER | SYMBOL | RATING | UNIT |
|-----------------------------|-------------------|-------------|------|
| Supply Voltage | V ⁺ /V | ±18 | V |
| Common Mode Input Voltage | V _{ICM} | ±15 (Note1) | V |
| Differential Input Voltage | V _{ID} | ±30 | V |
| Power Dissipation | P _D | 910 | mW |
| Output Current | I _O | ±25 | mA |
| Operating Temperature Range | T _{opr} | -40 to +85 | °C |
| Storage Temperature Range | T _{stg} | -50 to +150 | °C |

(Note1) For supply Voltages less than ±15 V, the maximum input voltage is equal to the Supply Voltage.

■ RECOMMENDED OPERATING CONDITION (Ta=25°C)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|----------------|-------------------|----------------|------|------|------|------|
| Supply Voltage | V ⁺ /V | - | ±9 | - | ±16 | V |

■ ELECTRIC CHARACTERISTICS

DC CHARACTERISTICS (V⁺/V=±15V, Ta=25°C unless otherwise specified)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|---------------------------------|------------------|---|------|-------|------|------|
| Operating Current | I _{cc} | No Signal, R _L =∞ | - | 8.5 | 12.0 | mA |
| Input Offset Voltage | V _{IO} | R _S ≤10kΩ (Note2, 3) | - | 0.8 | 5.0 | mV |
| Input Bias Current | I _B | (Note2, 3) | - | 200 | 800 | pA |
| Input Offset Current | I _{IO} | (Note2, 3) | - | 100 | 400 | pA |
| Voltage Gain | A _V | R _L ≥2kΩ, V _o =±10V | 90 | 105 | - | dB |
| Common Mode Rejection Ratio | CMR | V _{ICM} =±8V (Note4) | 60 | 75 | - | dB |
| Supply Voltage Rejection Ratio | SVR | V ⁺ /V ⁻ =±9.0 to ±16.0V (Note2, 5) | 70 | 83 | - | dB |
| Max Output Voltage 1 | V _{OM1} | R _L =10kΩ | ±12 | ±13.5 | - | V |
| Max Output Voltage 2 | V _{OM2} | R _L =2kΩ | ±10 | ±12.5 | - | V |
| Input Common Mode Voltage Range | V _{ICM} | CMR≥60dB | ±8 | ±9.5 | - | V |

(Note2) Measured at V_{ICM}=0V

(Note3) Written by the absolute rate.

(Note4) CMR is calculated by specified change in offset voltage. (V_{ICM}=0V to +8V and V_{ICM}=0V to -8V)

(Note5) SVR is calculated by specified change in offset voltage. (V⁺/V⁻=±9V to ±16V)

AC CHARACTERISTICS ($V^+/V^- = \pm 15V$, $T_a = 25^\circ C$ unless otherwise specified)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|---------------------------|----------|--|------|-------|------|----------------------------|
| Gain Bandwidth Product | GB | $f=10\text{kHz}$ | - | 3.3 | - | MHz |
| Unity Gain Frequency | f_T | $A_V=+100, R_S=100\Omega, R_L=2k\Omega, C_L=10\text{pF}$ | - | 3.0 | - | MHz |
| Phase Margin | ϕ_M | $A_V=+100, R_S=100\Omega, R_L=2k\Omega, C_L=10\text{pF}$ | - | 60 | - | deg |
| Input Noise Voltage1 | V_{NI} | $f=1\text{kHz}, A_V=+100, R_S=100\Omega$ | - | 9.5 | - | nV/ $\sqrt{\text{Hz}}$ |
| Input Noise Voltage2 | V_{N2} | RIAA, $R_S = 2.2k\Omega$, 30kHz LPF | - | 1.2 | 3.0 | μV_{rms} |
| Total Harmonic Distortion | THD | $f=1\text{kHz}, A_V=+10, R_L=2k\Omega, V_o=5\text{V}_{\text{rms}}$ | - | 0.002 | - | % |
| Channel Separation | CS | $f=1\text{kHz}, A_V=-+100, R_S=1k\Omega, R_L=2k\Omega$ | - | 150 | - | dB |
| Positive Slew Rate | +SR | $A_V=1, V_{IN}=2V_{pp}, R_L=2k\Omega, C_L=10\text{pF}$ | - | 12 | - | V/ μs |
| Negative Slew Rate | -SR | $A_V=1, V_{IN}=2V_{pp}, R_L=2k\Omega, C_L=10\text{pF}$ | - | 13 | - | V/ μs |

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■ Application Notes

• Package Power, Power Dissipation and Output Power

IC is heated by own operation and possibly gets damage when the junction power exceeds the acceptable value called Power Dissipation P_D . The dependence of the MUSES01 P_D on ambient temperature is shown in Fig 1. The plots are depended on following two points. The first is P_D on ambient temperature 25°C, which is the maximum power dissipation. The second is 0W, which means that the IC cannot radiate any more. Conforming the maximum junction temperature T_{jmax} to the storage temperature T_{stg} derives this point. Fig.1 is drawn by connecting those points and conforming the P_D lower than 25°C to it on 25°C. The P_D is shown following formula as a function of the ambient temperature between those points.

$$\text{Dissipation Power } P_D = \frac{T_{jmax} - T_a}{\theta_{ja}} \text{ [W]} \quad (\text{Ta}=25^\circ\text{C} \text{ to } \text{Ta}=150^\circ\text{C})$$

Where, θ_{ja} is heat thermal resistance which depends on parameters such as package material, frame material and so on. Therefore, P_D is different in each package.

While, the actual measurement of dissipation power on MUSES01 is obtained using following equation.

$$(\text{Actual Dissipation Power}) = (\text{Supply Voltage } V_{DD}) \times (\text{Supply Current } I_{DD}) - (\text{Output Power } P_o)$$

The MUSES01 should be operated in lower than P_D of the actual dissipation power.

To sustain the steady state operation, take account of the Dissipation Power and thermal design.

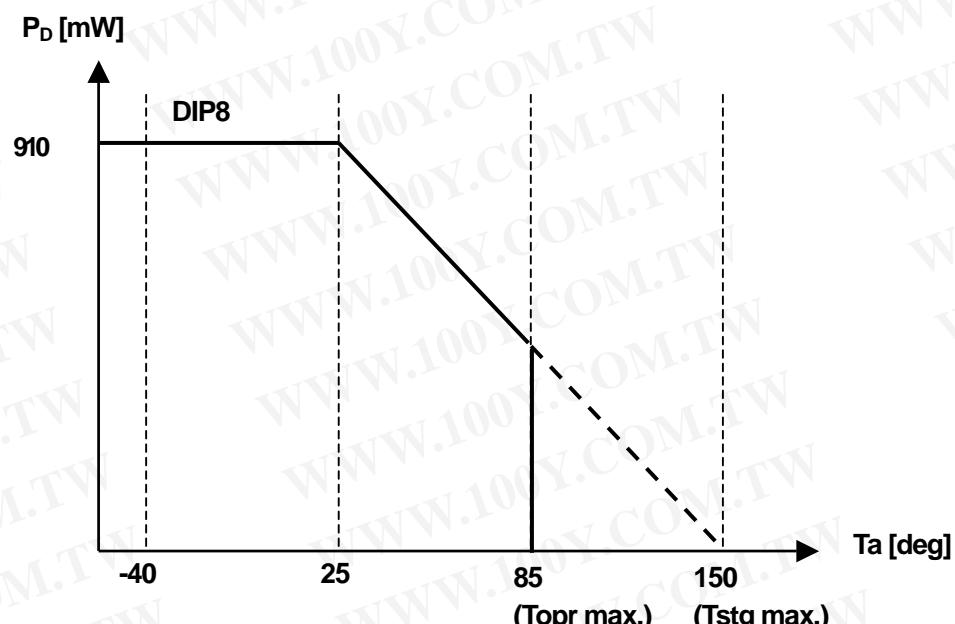
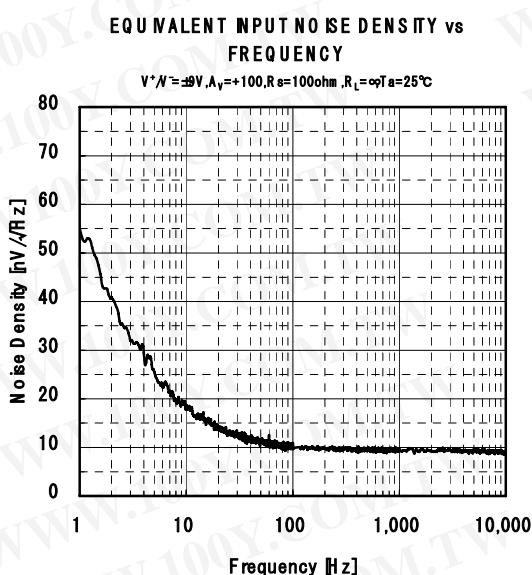
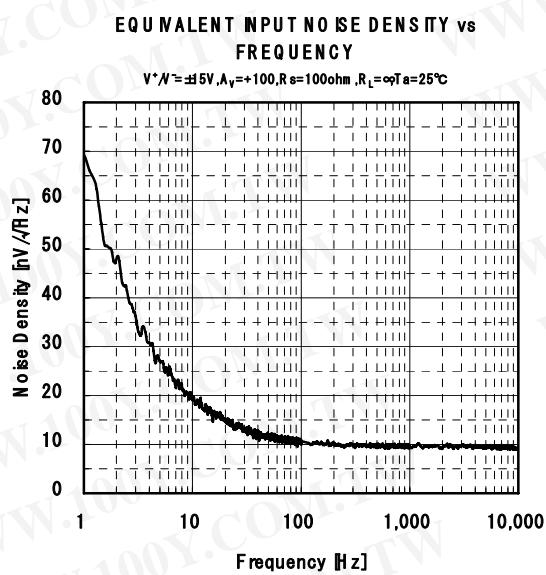
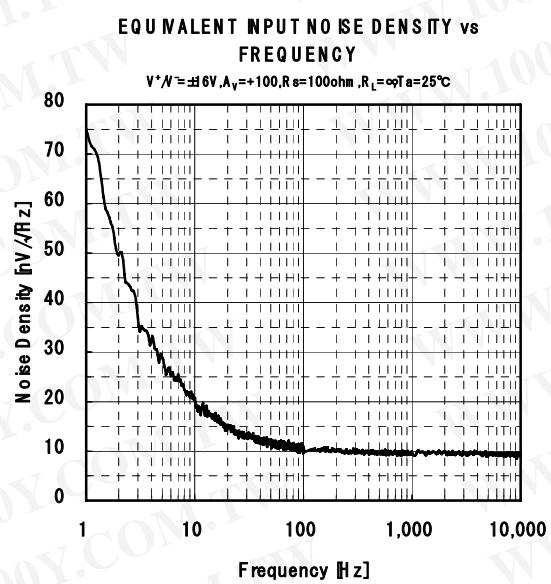
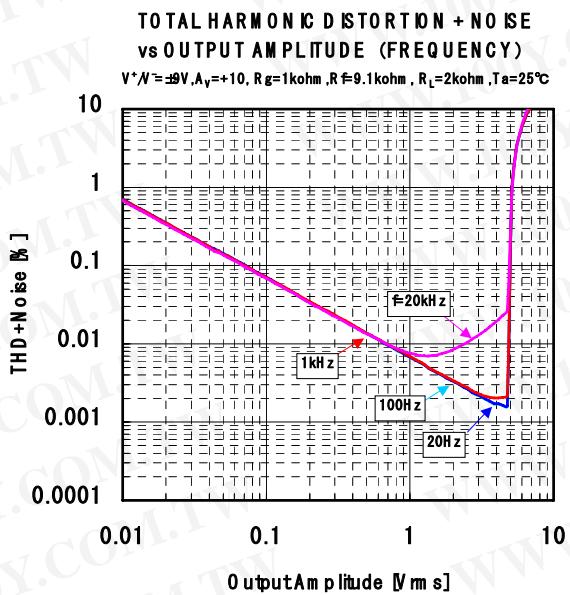
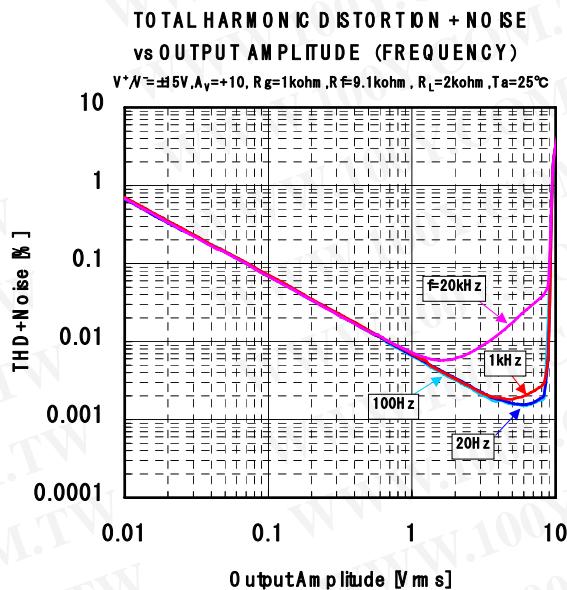
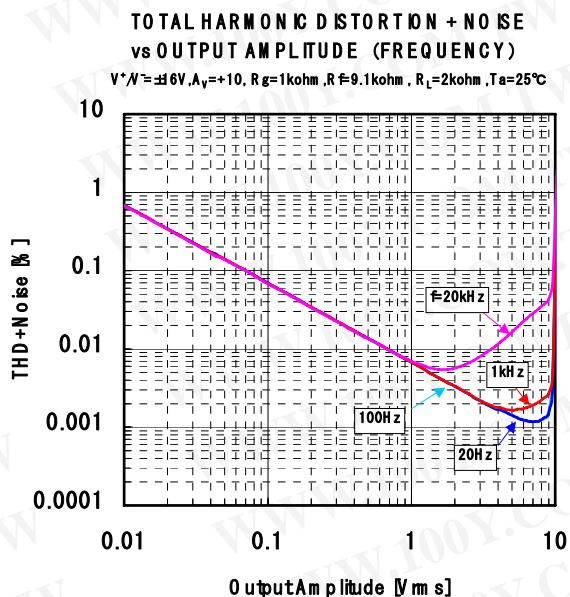


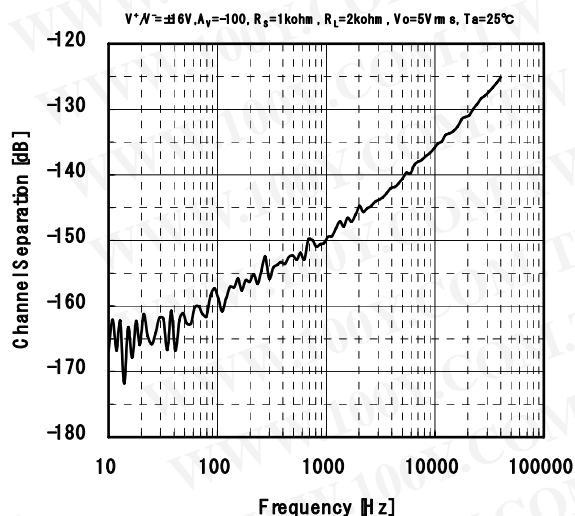
Fig.1 Power Dissipations vs. Ambient Temperature on the MUSES01

■ TYPICAL CHARACTERISTICS

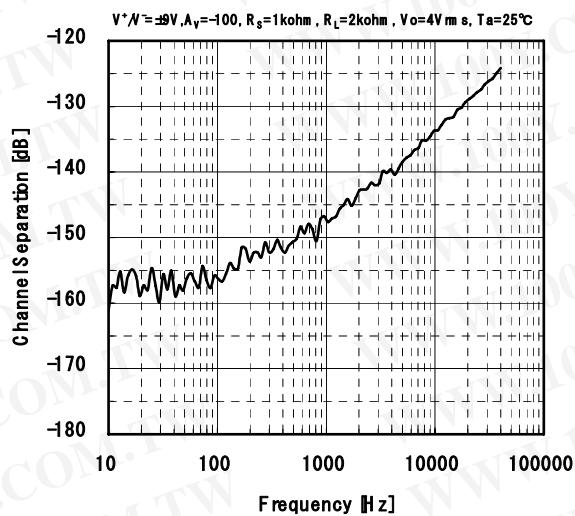


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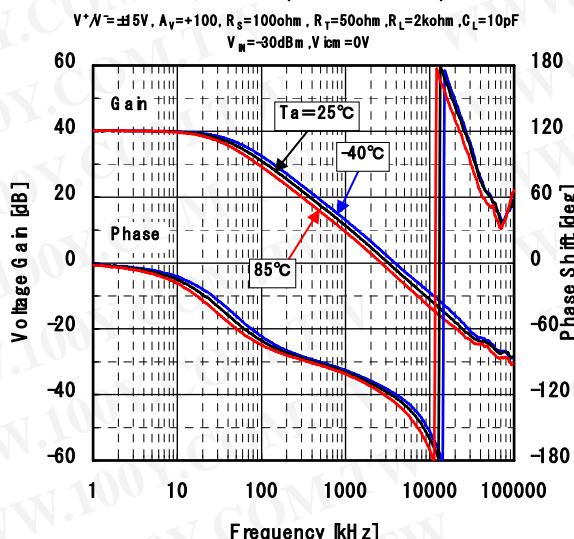
CHANNEL SEPARATION vs FREQUENCY



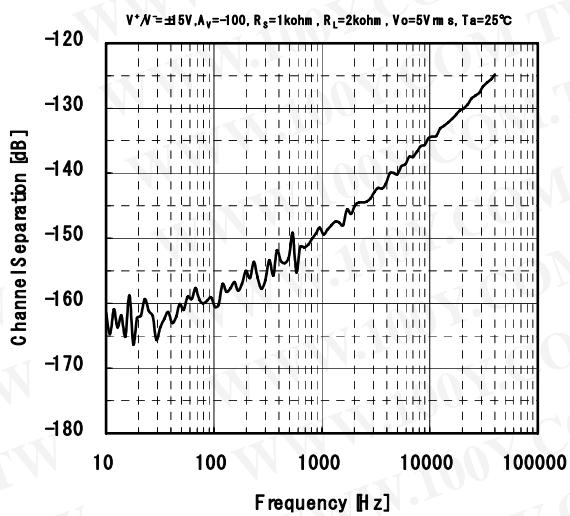
CHANNEL SEPARATION vs FREQUENCY



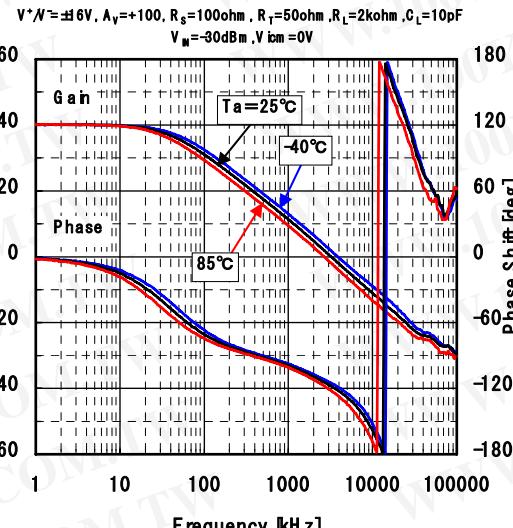
CLOSED-LOOP GAIN/PHASE vs FREQUENCY (TEMPERATURE)



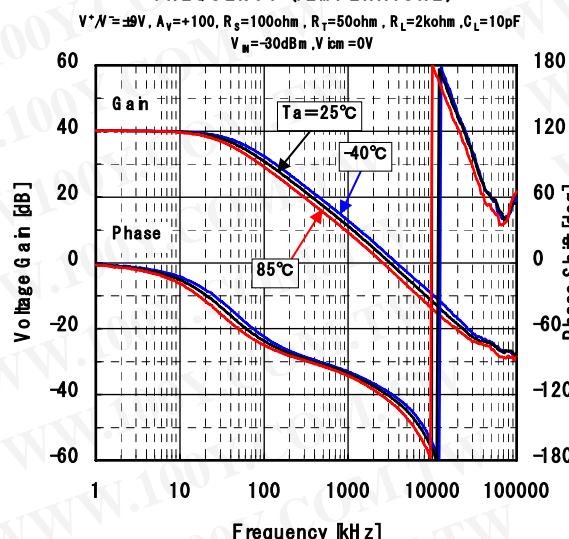
CHANNEL SEPARATION vs FREQUENCY



CLOSED-LOOP GAIN/PHASE vs FREQUENCY (TEMPERATURE)



CLOSED-LOOP GAIN/PHASE vs FREQUENCY (TEMPERATURE)



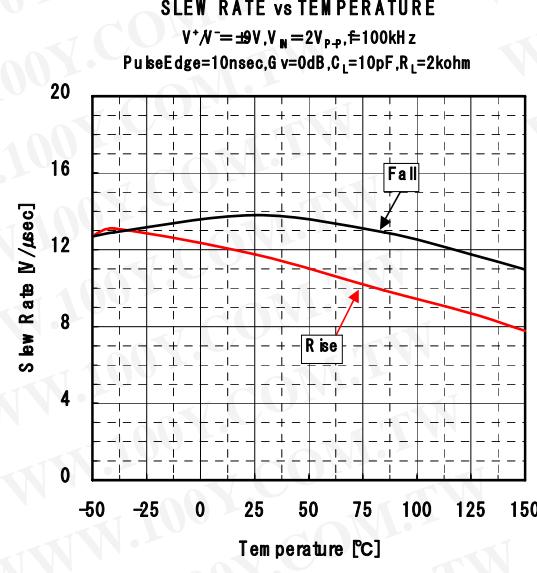
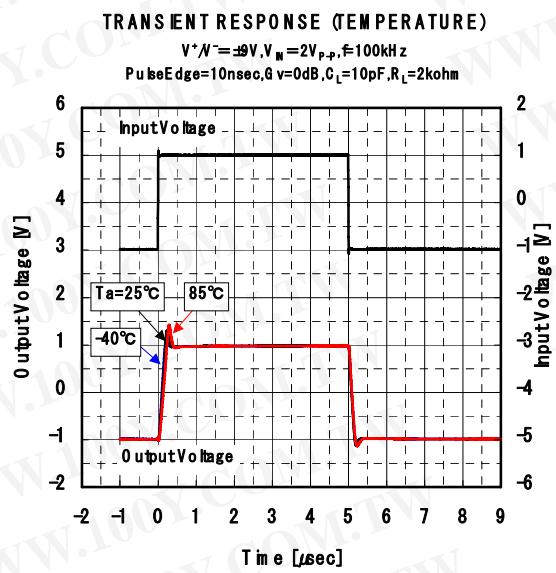
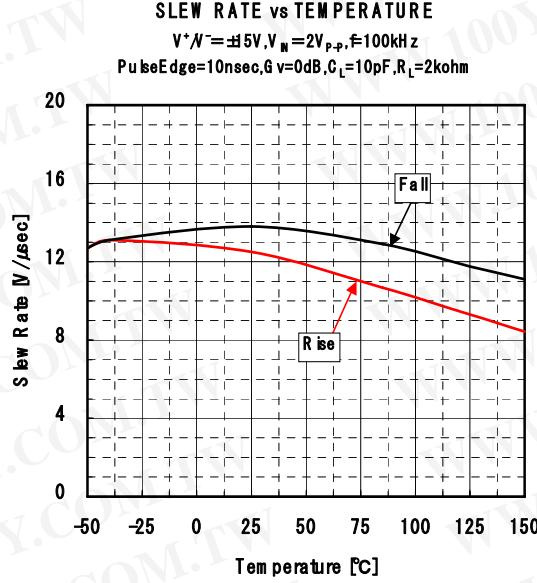
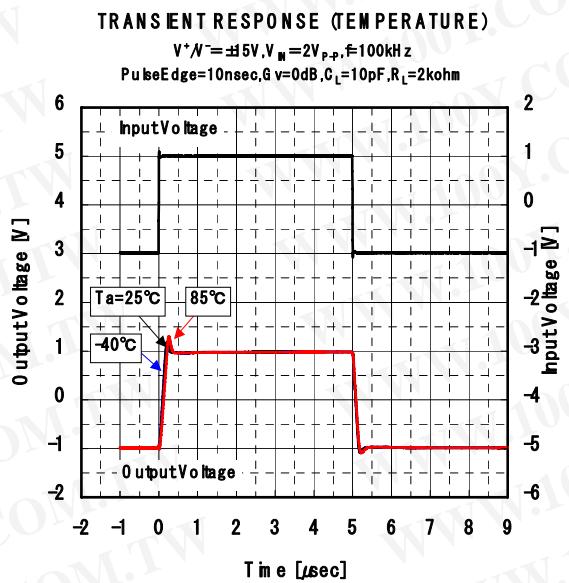
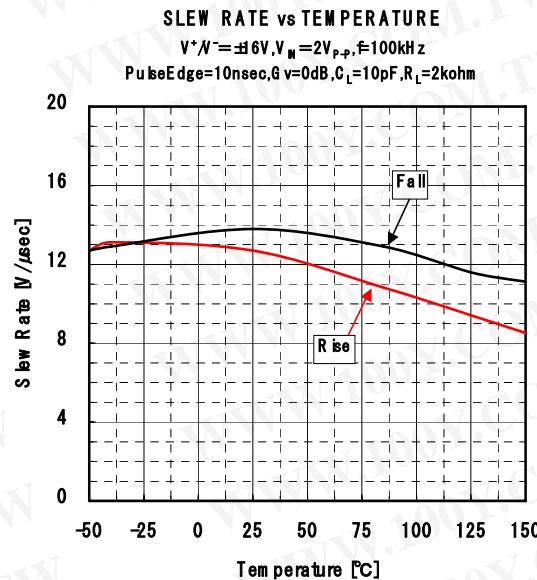
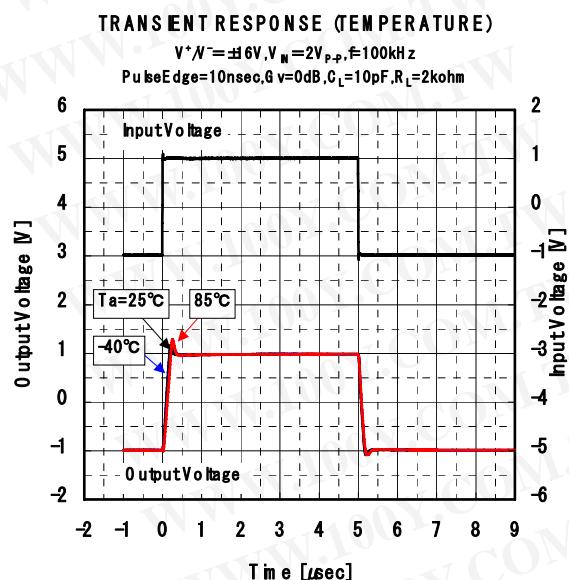
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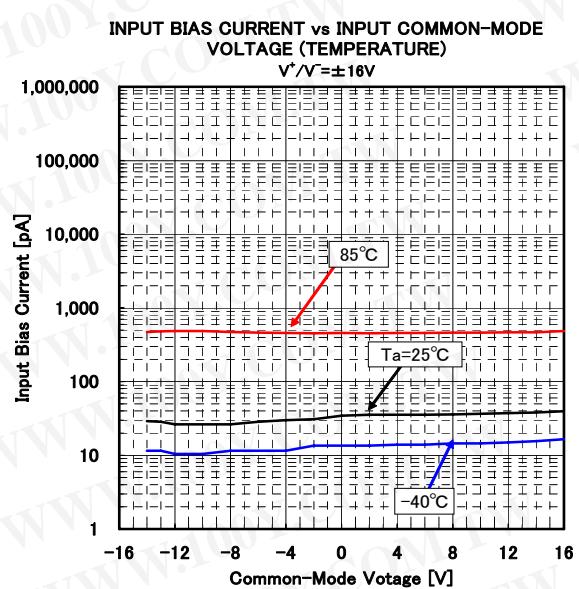
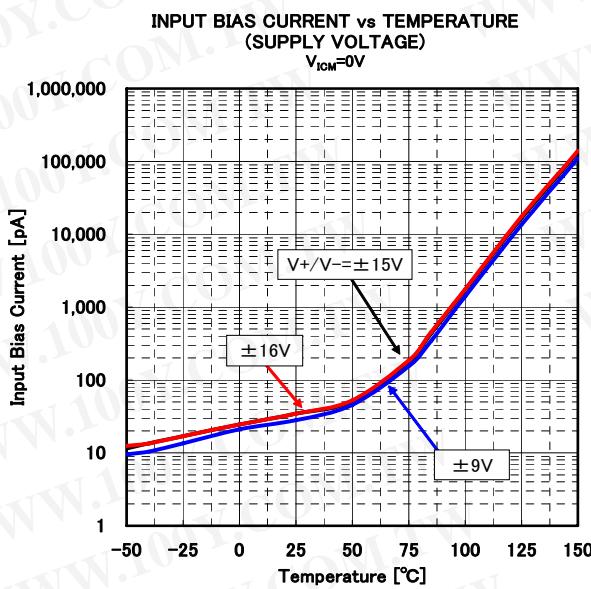
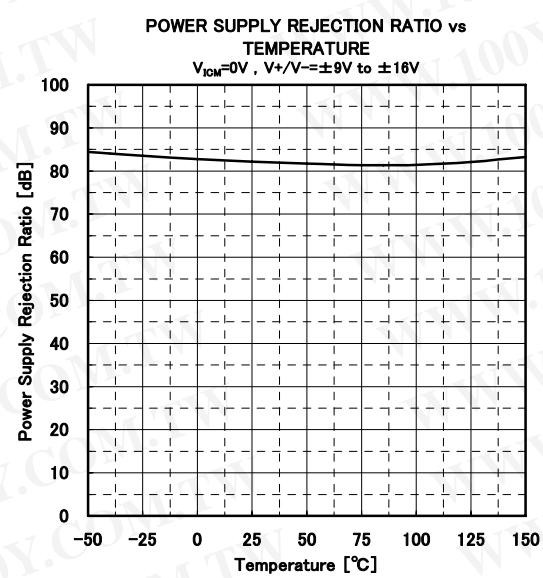
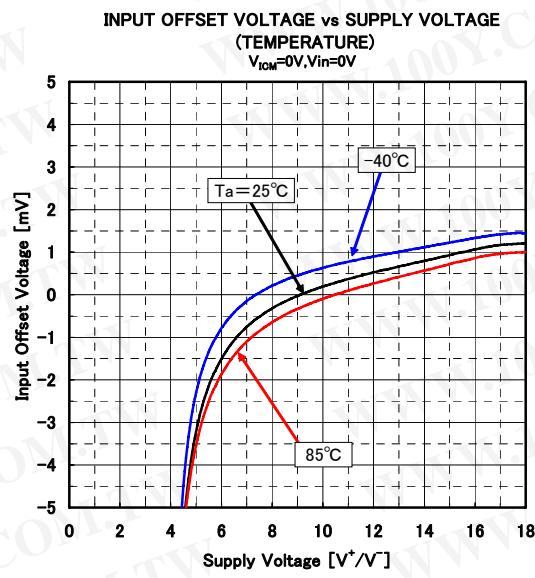
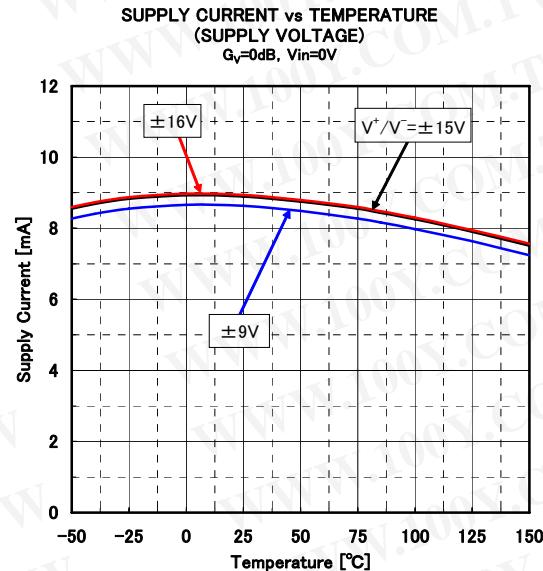
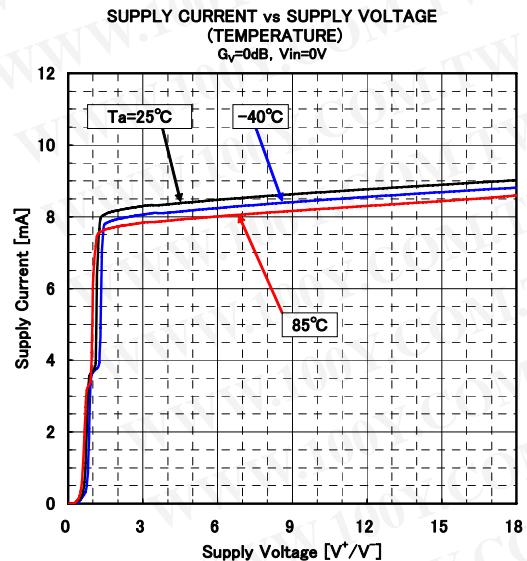
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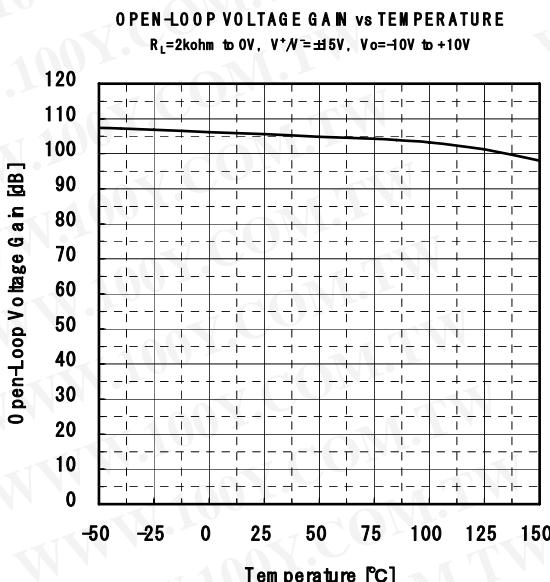
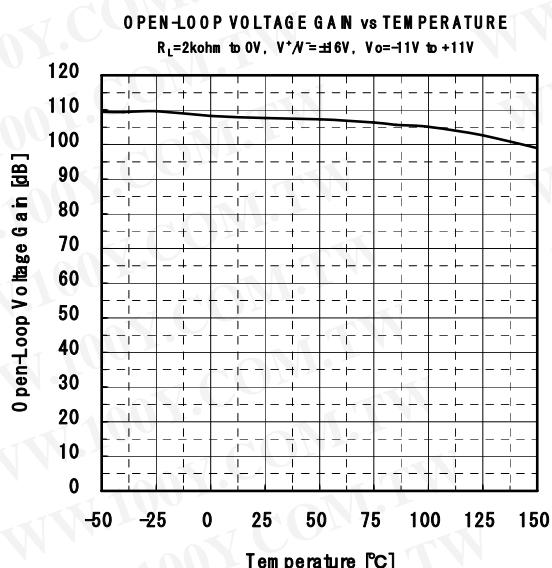
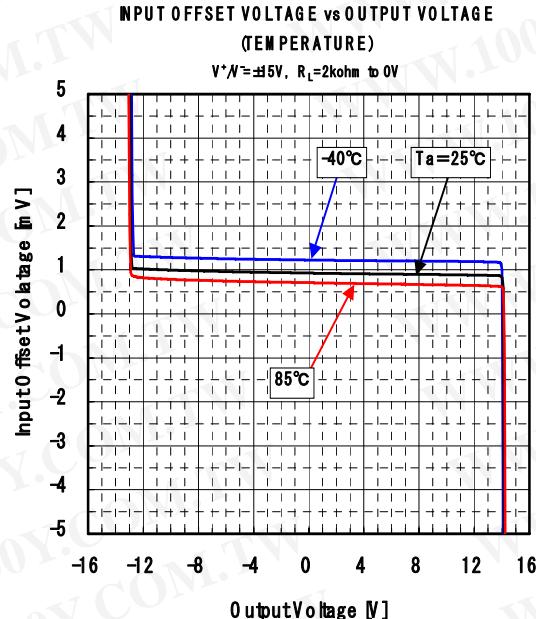
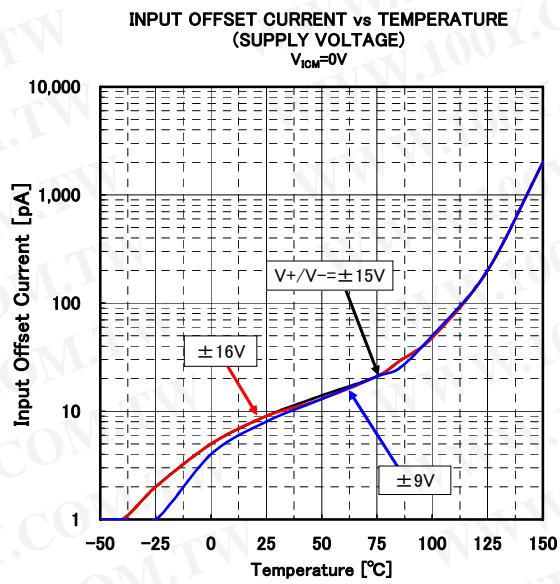
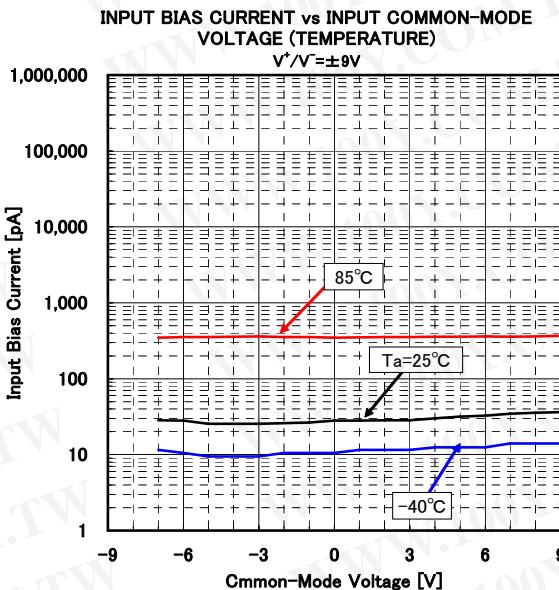
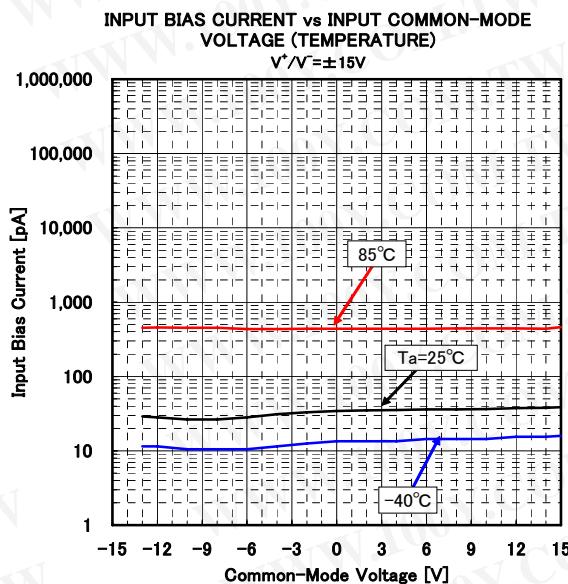


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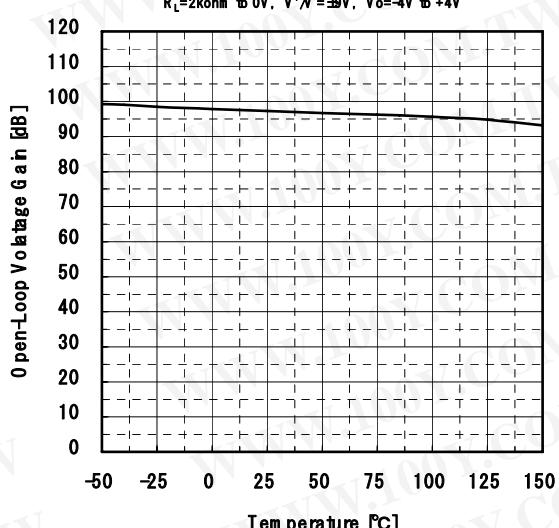
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OPEN-LOOP VOLTAGE GAIN vs TEMPERATURE

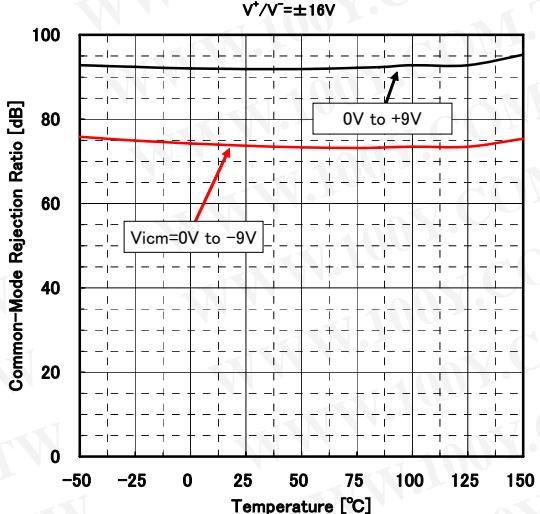
$R_L=2\text{kohm}$ to 0V, $V^+/V^-=\pm 9V$, $V_o=-4V$ to +4V



COMMON-MODE REJECTION RATIO vs TEMPERATUER

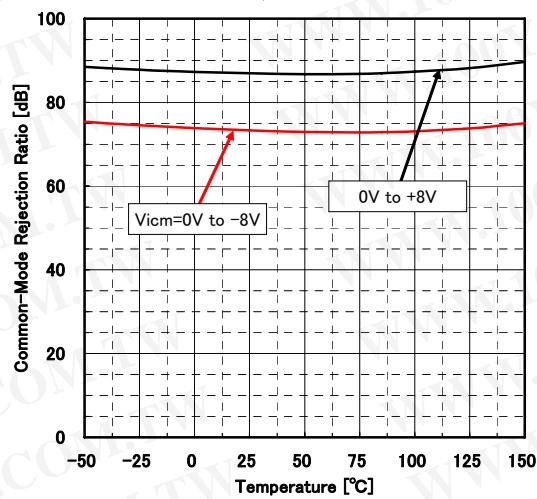
(INPUT COMMON-MODE VOLTAGE)

$V^+/V^-=\pm 16V$



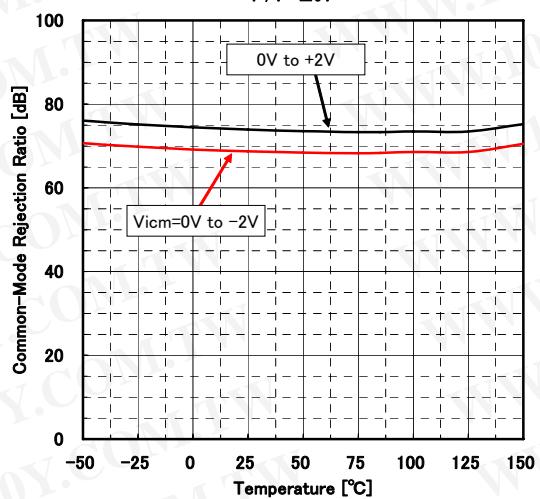
COMMON-MODE REJECTION RATIO vs TEMPERATURE (INPUT COMMON-MODE VOLTAGE)

$V^+/V^-=\pm 15V$



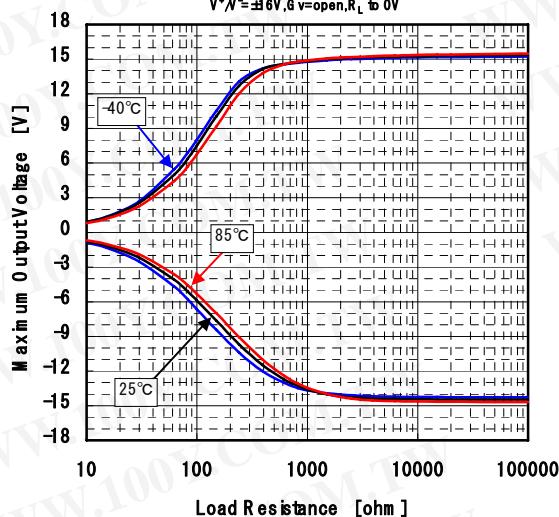
COMMON-MODE REJECTION RATIO vs TEMPERATURE (INPUT COMMON-MODE VOLTAGE)

$V^+/V^-=\pm 9V$



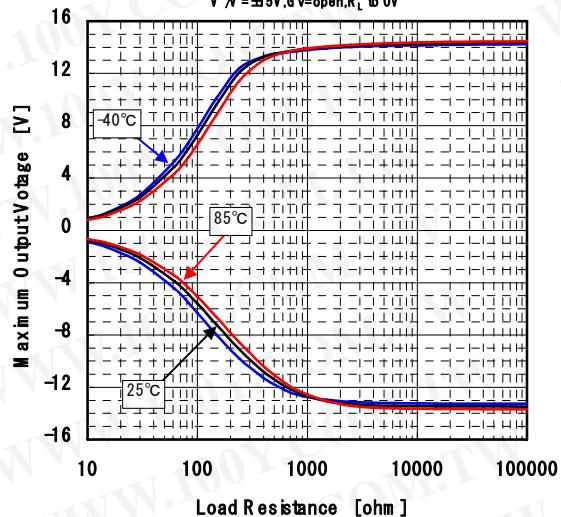
MAXIMUM OUTPUT VOLTAGE vs LOAD RESISTANCE (TEMPERATURE)

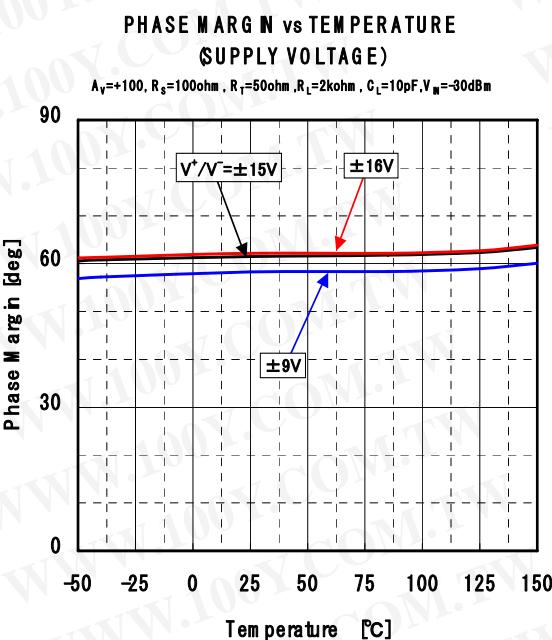
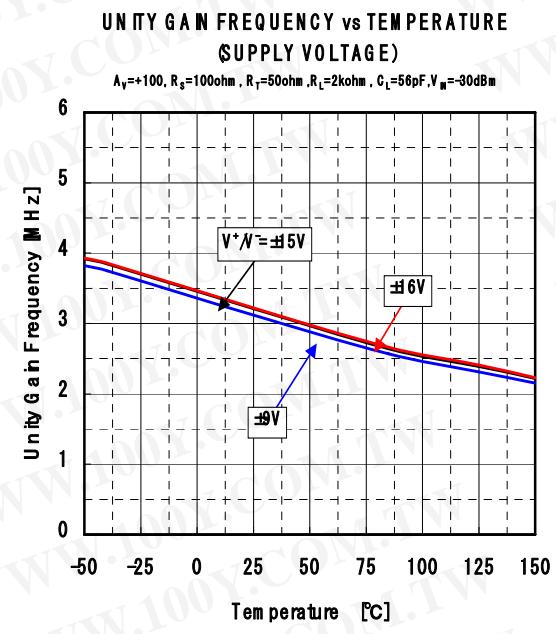
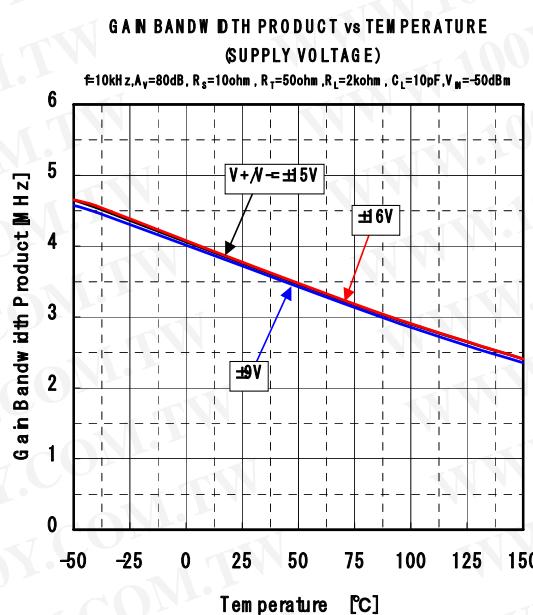
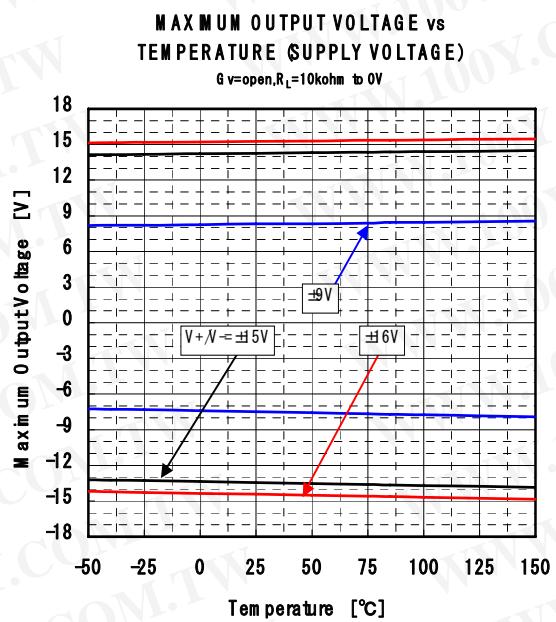
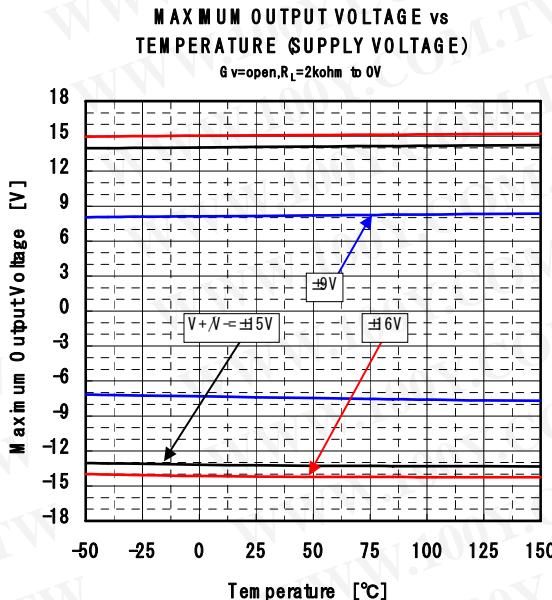
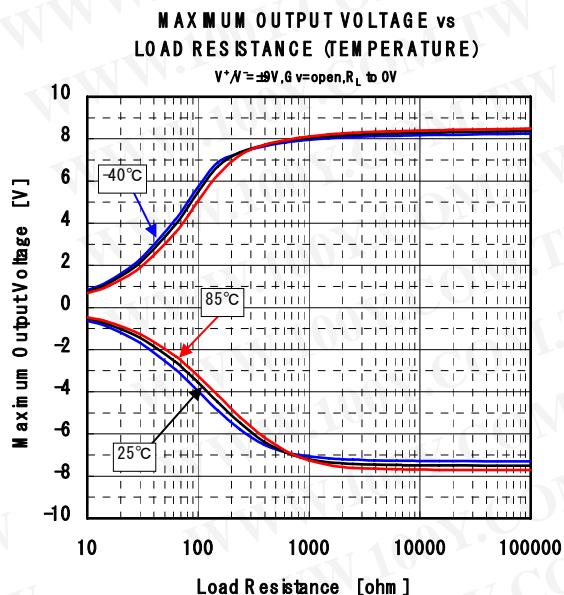
$V^+/V^-=\pm 16V$, $G_v=\text{open}$, R_L to 0V



MAXIMUM OUTPUT VOLTAGE vs LOAD RESISTANCE (TEMPERATURE)

$V^+/V^-=\pm 15V$, $G_v=\text{open}$, R_L to 0V





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